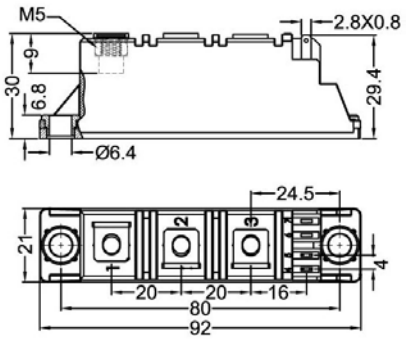
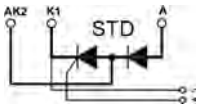
STD70GKxxB

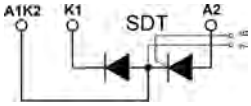
Thyristor-Diode Modules

Type	V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V
STD70GK08B	900	800
STD70GK12B	1300	1200
STD70GK14B	1500	1400
STD70GK16B	1700	1600
STD70GK18B	1900	1800

Dimensions in mm (1mm=0.0394")







Symbol	Test Conditions		Maximum Ratings	Unit
I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_C=85^oC$; 180° sine		110 70	A
I_{TSM}, I_{FSM}	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	1600 1700	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	1450 1540	
$\int i^2dt$	$T_{VJ}=45^oC$ $V_R=0$	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	13200 13990	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	9900 10500	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ f=50Hz, t_p=200us V_D=2/3V_{DRM} I_G=0.45A di_G/dt=0.45A/us	repetitive, $I_T=150A$ non repetitive, $I_T=I_{TAVM}$	150 500	A/us
$(dv/dt)_{cr}$	$T_{VJ}=T_{VJM}$; $R_{GK}=\infty$; method 1 (linear	V_{DR}=2/3V_{DRM} voltage rise)	1000	V/us
P_{GM}	$T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$	t_p=30us t_p=300us	10 5	W
P_{GAV}			0.5	W
V_{RGM}			10	V
T_{VJ} T_{VJM} T_{stg}			-40...+125 125 -40...+125	^oC
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq$1mA	t=1min t=1s	3000 3600	V~
M_d	Mounting torque (M5) Terminal connection torque (M5)		2.5-4.0/22-35 2.5-4.0/22-35	Nm/lb.in.
Weight	Typical including screws		120	g

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Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	5	mA
V_T, V_F	I_T, I_F=210A; $T_{VJ}=25^oC$	1.60	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^oC$)	0.85	V
r_T		3.7	mΩ
V_{GT}	V_D=6V; $T_{VJ}=25^oC$ $T_{VJ}=-40^oC$	1.5 1.6	V
I_{GT}	V_D=6V; $T_{VJ}=25^oC$ $T_{VJ}=-40^oC$	100 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; $V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_L	$T_{VJ}=25^oC$; t_p=10us; V_D=6V I_G=0.45A; di_G/dt=0.45A/us	450	mA
I_H	$T_{VJ}=25^oC$; V_D=6V; $R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^oC$; $V_D=1/2V_{DRM}$ I_G=0.45A; di_G/dt=0.45A/us	2	us
t_q	$T_{VJ}=T_{VJM}$; I_T=150A; t_p=200us; -di/dt=10A/us typ. V_R=100V; dv/dt=20V/us; $V_D=2/3V_{DRM}$	150	us
Q_S	$T_{VJ}=T_{VJM}$; I_T, I_F=50A; -di/dt=3A/us	100	uC
I_{RM}		24	A
R_{thJC}	per thyristor/diode; DC current per module	0.45 0.225	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.65 0.325	K/W
d_S	Creeping distance on surface	12.7	mm
d_A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES

* International standard package
* Copper base plate
* Glass passivated chips
* Isolation voltage 3600 V~
* UL file NO.310749
* RoHS compliant

APPLICATIONS

* DC motor control
* Softstart AC motor controller
* Light, heat and temperature control

ADVANTAGES

* Space and weight savings
* Simple mounting with two screws
* Improved temperature and power cycling
* Reduced protection circuits

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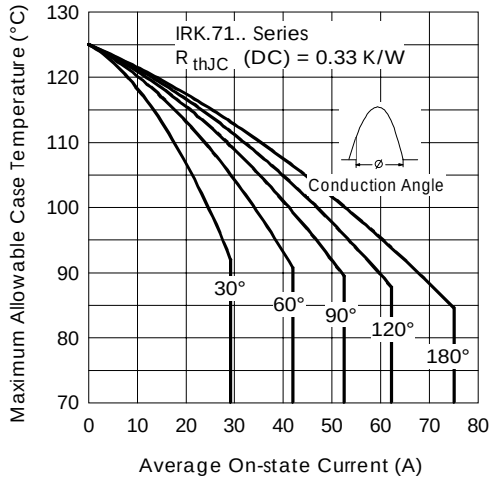

Fig. 1 - Current Ratings Characteristics

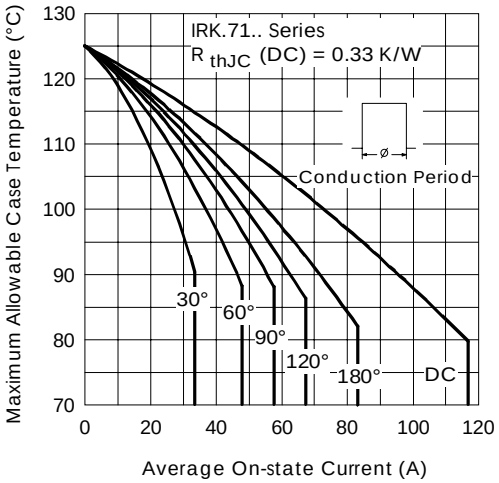

Fig. 2 - Current Ratings Characteristics

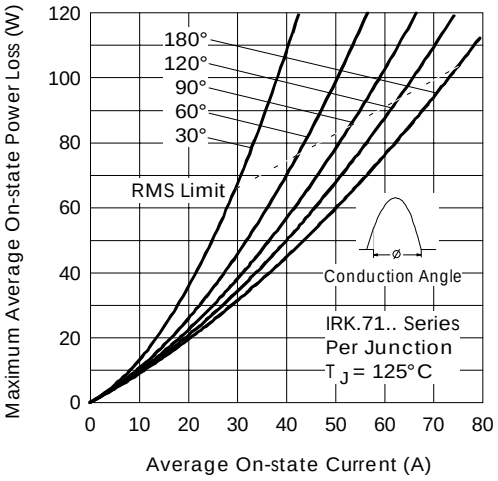

Fig. 3 - On-state Power Loss Characteristics

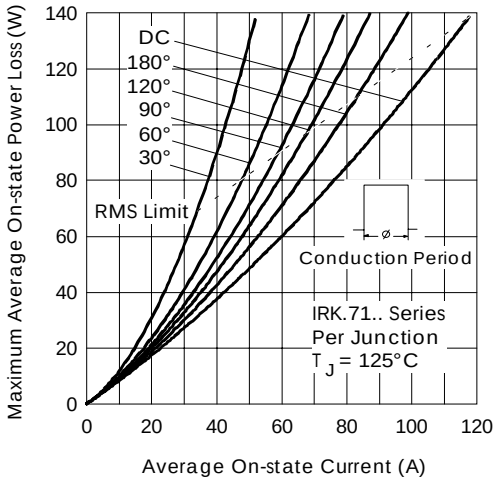

Fig. 4 - On-state Power Loss Characteristics

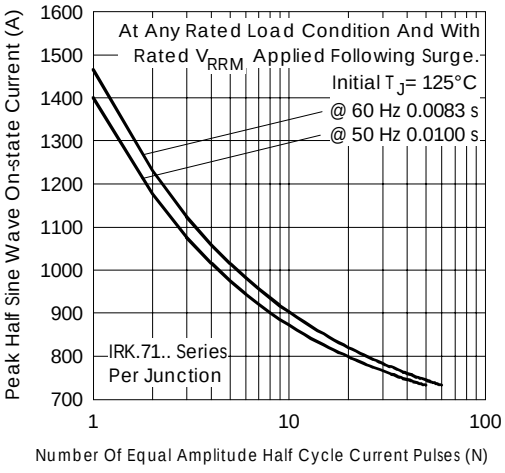

Fig. 5 - Maximum Non-Repetitive Surge Current

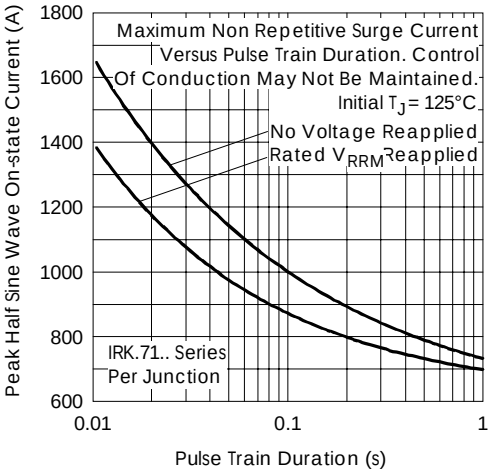

Fig. 6 - Maximum Non-Repetitive Surge Current

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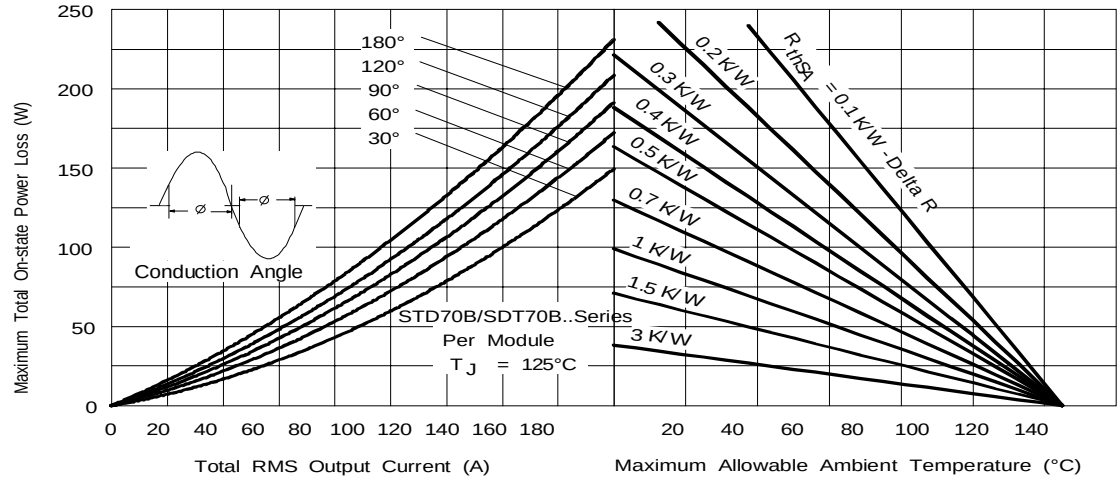

Fig. 7 - On-state Power Loss Characteristics

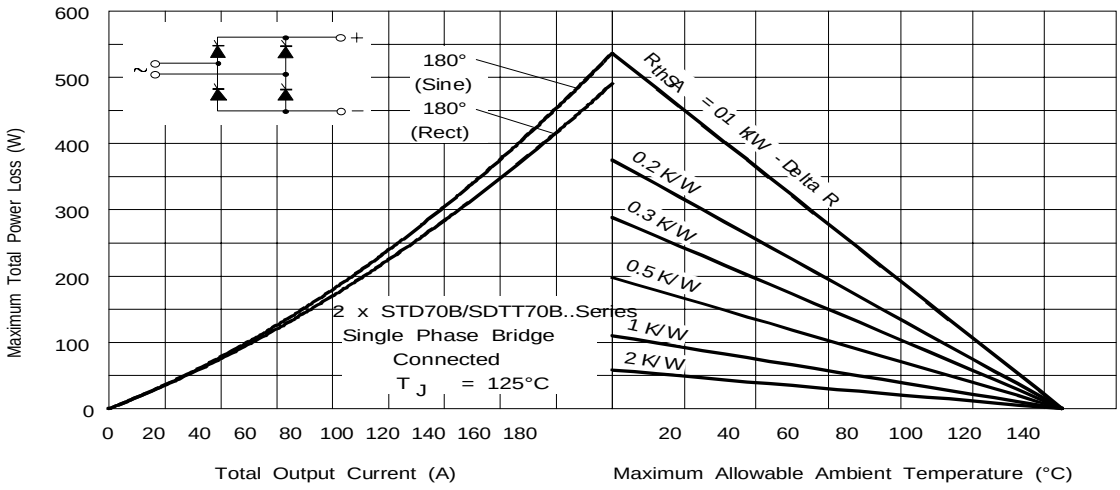

Fig. 8 - On-state Power Loss Characteristics

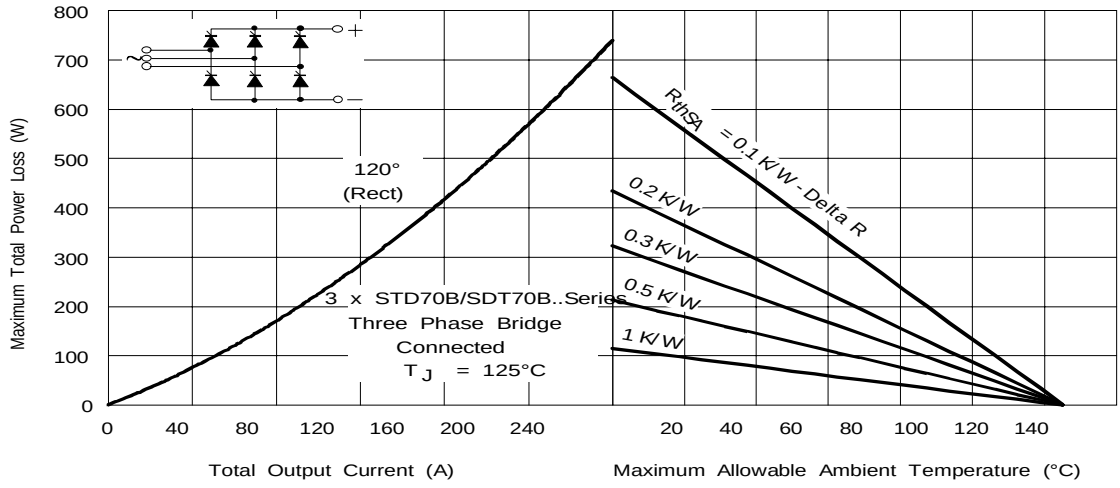

Fig. 9 - On-state Power Loss Characteristics

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